捷多邦,专业PCBI**SM54ALS小党A急SN7**4ALS112A DUAL J-K NEGATIVE-EDGE-TRIGGERED FLIP-FLOPS WITH CLEAR AND PRESET

SDAS199A - APRIL 1982 - REVISED DECEMBER 1994

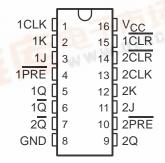
- Fully Buffered to Offer Maximum Isolation
 From External Disturbance
- Package Options Include Plastic Small-Outline (D) Packages, Ceramic Chip Carriers (FK), and Standard Plastic (N) and Ceramic (J) 300-mil DIPs

TYPE	TYPICAL MAXIMUM CLOCK FREQUENCY (MHz)	TYPICAL POWER DISSIPATION PER FLIP-FLOP (mW)
'ALS112A	50	6

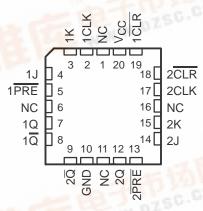
description

These devices contain two independent J-K negative-edge-triggered flip-flops. A low level at the preset (PRE) or clear (CLR) inputs sets or resets the outputs, regardless of the levels of the other inputs. When PRE and CLR are inactive (high), data at the J and K inputs meeting the setup-time requirements is transferred to the outputs on the negative-going edge of the clock pulse (CLK). Clock triggering occurs at a voltage level and is not directly related to the fall time of the clock pulse. Following the hold-time interval, data at the J and K inputs may be changed without affecting the levels at the outputs. These versatile flip-flops can perform as toggle flip-flops by tying J and K high.

SN54ALS112A . . . J PACKAGE SN74ALS112A . . . D OR N PACKAGE (TOP VIEW)



SN54ALS112A . . . FK PACKAGE (TOP VIEW)



NC - No internal connection

The SN54ALS112A is characterized for operation over the full military temperature range of –55°C to 125°C. The SN74ALS112A is characterized for operation from 0°C to 70°C.

FUNCTION TABLE (each flip-flop)

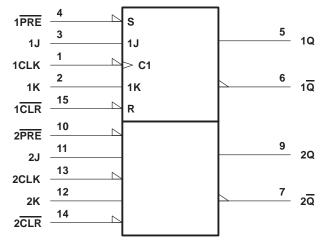
INPUTS					OUT	PUTS
PRE	CLR	CLK	J	K	Q	Q
L	Н	Х	Χ	Х	Н	L
Н	L	X	Χ	X	L	Н
L	L	X	Χ	X	H [†]	H [†]
Н	Н	\downarrow	L	L	Q ₀	\overline{Q}_0
Н	Н	\downarrow	Н	(PL	Н	L
Н	Н	1	L	Н	L	Н
H	SCH C	1	Н	Н	Toggle	
Н	Н	Н	Χ	Χ	Q_0	\overline{Q}_0

[†] The output levels in this configuration may not meet the minimum levels for V_{OH}. Furthermore, this configuration is nonstable; that is, it does not persist when either PRE or CLR returns to its inactive (high) level.

SN54ALS112A, SN74ALS112A DUAL J-K NEGATIVE-EDGE-TRIGGERED FLIP-FLOPS WITH CLEAR AND PRESET

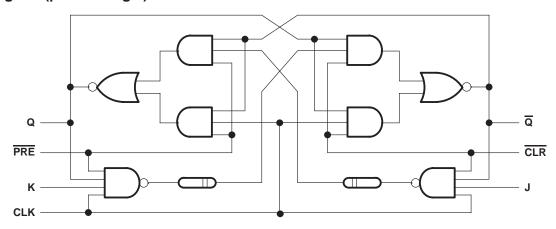
SDAS199A - APRIL 1982 - REVISED DECEMBER 1994

logic symbol†



[†] This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12. Pin numbers shown are for the D, J, and N packages.

logic diagram (positive logic)



absolute maximum ratings over operating free-air temperature range (unless otherwise noted)‡

	SN54ALS112A	
	SN74ALS112A	0°C to 70°C
Storage temperature range		. −65°C to 150°C

[‡] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.



SN54ALS112A, SN74ALS112A **DUAL J-K NEGATIVE-EDGE-TRIGGERED FLIP-FLOPS** WITH CLEAR AND PRESET

SDAS199A – APRIL 1982 – REVISED DECEMBER 1994

recommended operating conditions

			SN54ALS112A			SN74ALS112A			UNIT
			MIN	NOM	MAX	MIN	NOM	MAX	UNII
Vcc	Supply voltage		4.5	5	5.5	4.5	5	5.5	V
VIH	High-level input voltage		2			2			V
V_{IL}	Low-level input voltage				0.7			0.8	V
IOH	High-level output current				-0.4			-0.4	mA
lOL	Low-level output current				4			8	mA
fclock	Clock frequency		0		25	0		30	MHz
	Pulse duration	PRE or CLR low	15			10			
t _W		CLK high	20			16.5			ns
		CLK low	20			16.5			
	Coture time a hadaya CLK	Data	25			22			ns
t _{su}	Setup time before CLK↓	PRE or CLR inactive	22			20			115
th	Hold time after CLK↓	Data	0			0			ns
TA	Operating free-air temperature		-55		125	0		70	°C

electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER		TEST CONDITIONS		SN	SN54ALS112A			SN74ALS112A		
				MIN	TYP [†]	MAX	MIN	TYP†	MAX	UNIT
VIK		$V_{CC} = 4.5 \text{ V},$	$I_{ } = -18 \text{ mA}$			-1.5			-1.5	V
Vон		$V_{CC} = 4.5 \text{ V to } 5.5 \text{ V},$	$I_{OH} = -0.4 \text{ mA}$	V _{CC} -2	2		V _{CC} -2			V
VOL		V00 = 45 V	I _{OL} = 4 mA		0.25	0.4		0.25	0.4	V
		V _{CC} = 4.5 V	I _{OL} = 8 mA					0.35	0.5	V
1.	J, K, or CLK	V 55V	5.5 V, V _I = 7 V			0.1			0.1	A
Ħ	PRE or CLR	V _{CC} = 5.5 V,				0.2			0.2	mA
lu.	J, K, or CLK	V 55V	V _I = 2.7 V			20			20	^
IН	PRE or CLR	V _{CC} = 5.5 V,				40			40	μΑ
Li	J, K, or CLK				-0.2			-0.2	A	
ll l	PRE or CLR		V = 0.4 V			-0.4			-0.4	mA
IO [‡]	-	V _{CC} = 5.5 V,	V _O = 2.25 V	-20		-112	-30		-112	mA
ICC		V _{CC} = 5.5 V,	See Note 1		2.5	4.5		2.5	4.5	mA



[†] All typical values are at V_{CC} = 5 V, T_A = 25°C. ‡ The output conditions have been chosen to produce a current that closely approximates one half of the true short-circuit output current, I_{OS}. NOTE 1: I_{CC} is measured with J, K, CLK, and PRE grounded, then with J, K, CLK, and CLR grounded.

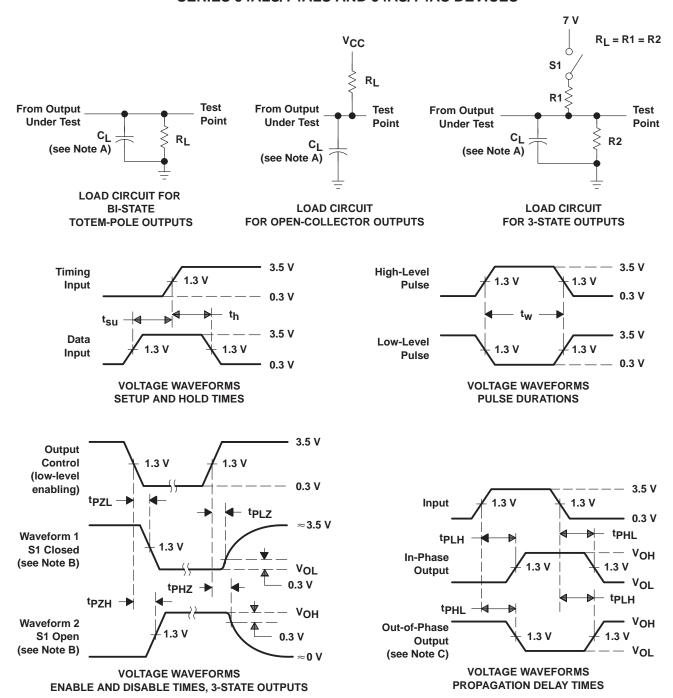
SN54ALS112A, SN74ALS112A DUAL J-K NEGATIVE-EDGE-TRIGGERED FLIP-FLOPS WITH CLEAR AND PRESET SDAS199A - APRIL 1982 - REVISED DECEMBER 1994

switching characteristics (see Figure 1)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	V_{CC} = 4.5 V to 5.5 V, C_L = 50 pF, R_L = 500 Ω , T_A = MIN to MAX [†]				UNIT
		` ′	SN54ALS112A		SN74ALS112A		
			MIN	MAX	MIN	MAX	
f _{max}			25		30		MHz
t _{PLH}	PRE or CLR	r CLR Q or Q	3	26	3	15	ns
^t PHL	PRE OF CLR		4	23	4	18	115
t _{PLH}	CLK	Q or $\overline{\mathbb{Q}}$	3	23	3	15	ns
t _{PHL}	OLK	QUIQ	5	24	5	19	115

[†] For conditions shown as MIN or MAX, use the appropriate value specified under recommended operating conditions.

PARAMETER MEASUREMENT INFORMATION SERIES 54ALS/74ALS AND 54AS/74AS DEVICES



NOTES: A. C_L includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
- C. When measuring propagation delay items of 3-state outputs, switch S1 is open.
- D. All input pulses have the following characteristics: $PRR \le 1$ MHz, $t_r = t_f = 2$ ns, duty cycle = 50%.
- E. The outputs are measured one at a time with one transition per measurement.

Figure 1. Load Circuits and Voltage Waveforms



IMPORTANT NOTICE

Texas Instruments and its subsidiaries (TI) reserve the right to make changes to their products or to discontinue any product or service without notice, and advise customers to obtain the latest version of relevant information to verify, before placing orders, that information being relied on is current and complete. All products are sold subject to the terms and conditions of sale supplied at the time of order acknowledgement, including those pertaining to warranty, patent infringement, and limitation of liability.

TI warrants performance of its semiconductor products to the specifications applicable at the time of sale in accordance with TI's standard warranty. Testing and other quality control techniques are utilized to the extent TI deems necessary to support this warranty. Specific testing of all parameters of each device is not necessarily performed, except those mandated by government requirements.

CERTAIN APPLICATIONS USING SEMICONDUCTOR PRODUCTS MAY INVOLVE POTENTIAL RISKS OF DEATH, PERSONAL INJURY, OR SEVERE PROPERTY OR ENVIRONMENTAL DAMAGE ("CRITICAL APPLICATIONS"). TI SEMICONDUCTOR PRODUCTS ARE NOT DESIGNED, AUTHORIZED, OR WARRANTED TO BE SUITABLE FOR USE IN LIFE-SUPPORT DEVICES OR SYSTEMS OR OTHER CRITICAL APPLICATIONS. INCLUSION OF TI PRODUCTS IN SUCH APPLICATIONS IS UNDERSTOOD TO BE FULLY AT THE CUSTOMER'S RISK.

In order to minimize risks associated with the customer's applications, adequate design and operating safeguards must be provided by the customer to minimize inherent or procedural hazards.

TI assumes no liability for applications assistance or customer product design. TI does not warrant or represent that any license, either express or implied, is granted under any patent right, copyright, mask work right, or other intellectual property right of TI covering or relating to any combination, machine, or process in which such semiconductor products or services might be or are used. TI's publication of information regarding any third party's products or services does not constitute TI's approval, warranty or endorsement thereof.

Copyright © 1998, Texas Instruments Incorporated